



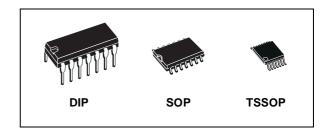
HEX INVERTER

- HIGH SPEED:
 - t_{PD} = 8ns (TYP.) at V_{CC} = 6V
- LOW POWER DISSIPATION: $I_{CC} = 1\mu A(MAX.)$ at $T_A=25^{\circ}C$
- HIGH NOISE IMMUNITY: V_{NIH} = V_{NIL} = 28 % V_{CC} (MIN.)
- SYMMETRICAL OUTPUT IMPEDANCE: $|I_{OH}| = I_{OL} = 4\text{mA}$ (MIN) at $V_{CC} = 4.5\text{V}$
- BALANCED PROPAGATION DELAYS: t_{PLH} ≅ t_{PHL}
- WIDE OPERATING VOLTAGE RANGE: V_{CC} (OPR) = 2V to 6V
- PIN AND FUNCTION COMPATIBLE WITH 74 SERIES 04



The M74HC04 is an high speed CMOS HEX INVERTER fabricated with silicon gate C²MOS technology.

The internal circuit is composed of 3 stages including buffer output, which enables high noise immunity and stable output.

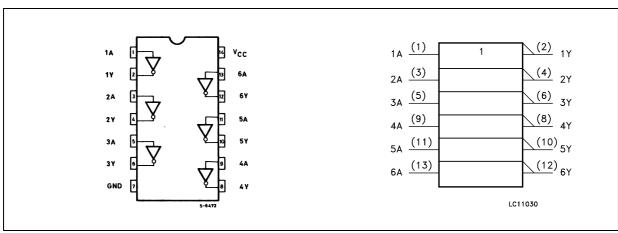


ORDER CODES

| PACKAGE | TUBE | T & R |
|---------|------------|---------------|
| DIP | M74HC04B1R | |
| SOP | M74HC04M1R | M74HC04RM13TR |
| TSSOP | | M74HC04TTR |

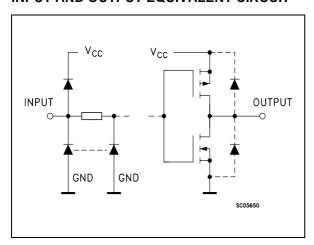
All inputs are equipped with protection circuits against static discharge and transient excess voltage.

PIN CONNECTION AND IEC LOGIC SYMBOLS



July 2001 1/8

INPUT AND OUTPUT EQUIVALENT CIRCUIT



PIN DESCRIPTION

| PIN No | SYMBOL | NAME AND FUNCTION |
|-----------------------|-----------------|-------------------------|
| 1, 3, 5, 9, 11, 13 | 1A to 6A | Data Inputs |
| 2, 4, 6, 8, 10, 12 | 1Y to 6Y | Data Outputs |
| 7 | GND | Ground (0V) |
| 14 | V _{CC} | Positive Supply Voltage |

TRUTH TABLE

| Α | Υ |
|---|---|
| L | Н |
| Н | L |

ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
|-------------------------------------|--------------------------------------|-------------------------------|------|
| V _{CC} | Supply Voltage | -0.5 to +7 | V |
| V _I | DC Input Voltage | -0.5 to V _{CC} + 0.5 | V |
| V _O | DC Output Voltage | -0.5 to V _{CC} + 0.5 | V |
| I _{IK} | DC Input Diode Current | ± 20 | mA |
| I _{OK} | DC Output Diode Current | ± 20 | mA |
| Io | DC Output Current | ± 25 | mA |
| I _{CC} or I _{GND} | DC V _{CC} or Ground Current | ± 50 | mA |
| P_{D} | Power Dissipation | 500(*) | mW |
| T _{stg} | Storage Temperature | -65 to +150 | °C |
| TL | Lead Temperature (10 sec) | 300 | °C |

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied (*) 500mW at 65 °C; derate to 300mW by 10mW/°C from 65°C to 85°C

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | Value | Unit | |
|-----------------|--------------------------|------------------------|----------------------|----|
| V _{CC} | Supply Voltage | | 2 to 6 | V |
| V _I | Input Voltage | | 0 to V _{CC} | V |
| Vo | Output Voltage | | 0 to V _{CC} | V |
| T _{op} | Operating Temperature | | -55 to 125 | °C |
| | Input Rise and Fall Time | $V_{CC} = 2.0V$ | 0 to 1000 | ns |
| t_r , t_f | | V _{CC} = 4.5V | 0 to 500 | ns |
| | | V _{CC} = 6.0V | 0 to 400 | ns |

DC SPECIFICATIONS

| | | Т | est Condition | | | | Value | | | | |
|-----------------|-----------------------------|-----|-------------------------|------|-----------------------|-------|-------------|------|--------------|------|------|
| Symbol | Parameter V _{CC} | | | Т | T _A = 25°C | | -40 to 85°C | | -55 to 125°C | | Unit |
| | | (V) | | Min. | Тур. | Max. | Min. | Max. | Min. | Max. | |
| V _{IH} | High Level Input | 2.0 | | 1.5 | | | 1.5 | | 1.5 | | |
| | Voltage | 4.5 | | 3.15 | | | 3.15 | | 3.15 | | V |
| | | 6.0 | | 4.2 | | | 4.2 | | 4.2 | | |
| V_{IL} | Low Level Input | 2.0 | | | | 0.5 | | 0.5 | | 0.5 | |
| | Voltage | 4.5 | | | | 1.35 | | 1.35 | | 1.35 | V |
| | | 6.0 | | | | 1.8 | | 1.8 | | 1.8 | |
| V _{OH} | High Level Output | 2.0 | I _O =-20 μA | 1.9 | 2.0 | | 1.9 | | 1.9 | | |
| | Voltage | 4.5 | I _O =-20 μA | 4.4 | 4.5 | | 4.4 | | 4.4 | | |
| | | 6.0 | I _O =-20 μA | 5.9 | 6.0 | | 5.9 | | 5.9 | | V |
| | | 4.5 | I _O =-4.0 mA | 4.18 | 4.31 | | 4.13 | | 4.10 | | |
| | | 6.0 | I _O =-5.2 mA | 5.68 | 5.8 | | 5.63 | | 5.60 | | |
| V _{OL} | Low Level Output | 2.0 | I _O =20 μA | | 0.0 | 0.1 | | 0.1 | | 0.1 | |
| | Voltage | 4.5 | I _O =20 μA | | 0.0 | 0.1 | | 0.1 | | 0.1 | |
| | | 6.0 | I _O =20 μA | | 0.0 | 0.1 | | 0.1 | | 0.1 | V |
| | | 4.5 | I _O =4.0 mA | | 0.17 | 0.26 | | 0.33 | | 0.40 | |
| | | 6.0 | I _O =5.2 mA | | 0.18 | 0.26 | | 0.33 | | 0.40 | |
| I _I | Input Leakage Current | 6.0 | $V_I = V_{CC}$ or GND | | | ± 0.1 | | ± 1 | | ± 1 | μΑ |
| I _{CC} | Quiescent Supply Current | 6.0 | $V_I = V_{CC}$ or GND | | | 1 | | 10 | | 20 | μА |

AC ELECTRICAL CHARACTERISTICS ($C_L = 50 \text{ pF}$, Input $t_r = t_f = 6 \text{ns}$)

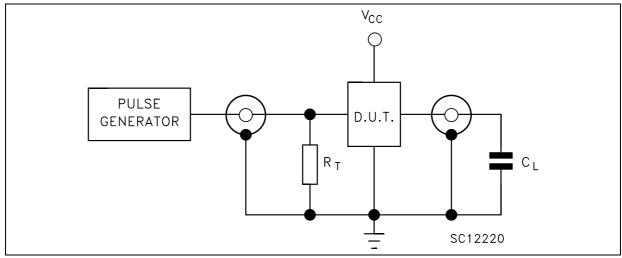
| | | 7 | Test Condition | | Value | | | | | | | |
|-----------------------------------|---------------------|-----------------|----------------|-----------------------|-------|------|-------------|------|--------------|-----|------|--|
| Symbol | Parameter | V _{CC} | Vcc | T _A = 25°C | | | -40 to 85°C | | -55 to 125°C | | Unit | |
| | V _{CC} (V) | Min. | Тур. | Max. | Min. | Max. | Min. | Max. | | | | |
| t _{tLH} t _{tHL} | Output Transition | 2.0 | | | 38 | 75 | | 95 | | 110 | | |
| | Time | 4.5 | | | 8 | 15 | | 19 | | 22 | ns | |
| | | 6.0 | | | 6 | 13 | | 16 | | 19 | | |
| t _{PLH} t _{PHL} | Propagation Delay | 2.0 | | | 45 | 95 | | 120 | | 145 | | |
| | Time | 4.5 | | | 9 | 19 | | 24 | | 29 | ns | |
| | | 6.0 | | | 8 | 16 | | 20 | | 25 | | |

CAPACITIVE CHARACTERISTICS

| | | 1 | Test Condition | | Value | | | | | | | | | |
|-----------------|--|-----------------|-----------------|-----------------|-----------------|------|------|-----------------------|------|-------------|----|--------------|--|------|
| Symbol | Parameter | V _{CC} | V _{CC} | v _{cc} | V _{CC} | | T, | Γ _A = 25°C | | -40 to 85°C | | -55 to 125°C | | Unit |
| | | (V) | (V) | Min. | Тур. | Max. | Min. | Max. | Min. | Max. | | | | |
| C _{IN} | Input Capacitance | 5.0 | | | 5 | 10 | | 10 | | 10 | pF | | | |
| C _{PD} | Power Dissipation Capacitance (note 1) | 5.0 | | | 22 | | | | | | pF | | | |

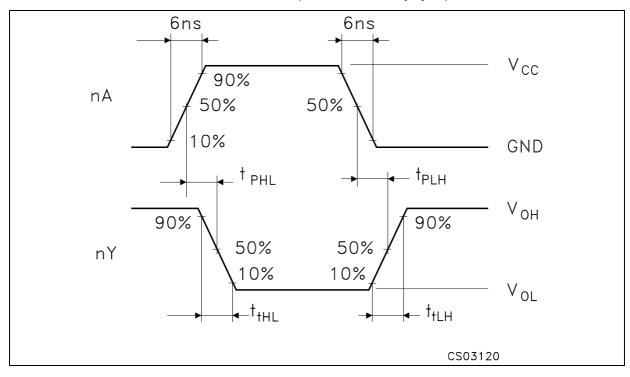
¹⁾ C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation. I_{CC(opr)} = C_{PD} x V_{CC} x f_{IN} + I_{CC}/6 (per Gate) 4

TEST CIRCUIT



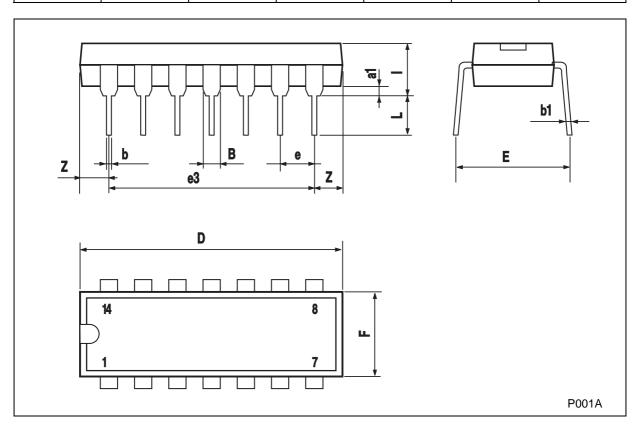
 C_L = 50pF or equivalent (includes jig and probe capacitance) R_T = Z_{OUT} of pulse generator (typically 50Ω)

WAVEFORM: PROPAGATION DELAY TIMES (f=1MHz; 50% duty cycle)



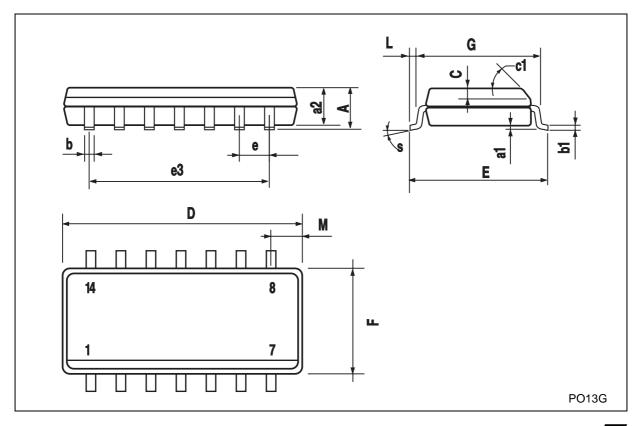
Plastic DIP-14 MECHANICAL DATA

| DIM | | mm. | | | inch | |
|------|------|-------|------|-------|-------|-------|
| DIM. | MIN. | TYP | MAX. | MIN. | TYP. | MAX. |
| a1 | 0.51 | | | 0.020 | | |
| В | 1.39 | | 1.65 | 0.055 | | 0.065 |
| b | | 0.5 | | | 0.020 | |
| b1 | | 0.25 | | | 0.010 | |
| D | | | 20 | | | 0.787 |
| E | | 8.5 | | | 0.335 | |
| е | | 2.54 | | | 0.100 | |
| e3 | | 15.24 | | | 0.600 | |
| F | | | 7.1 | | | 0.280 |
| I | | | 5.1 | | | 0.201 |
| L | | 3.3 | | | 0.130 | |
| Z | 1.27 | | 2.54 | 0.050 | | 0.100 |



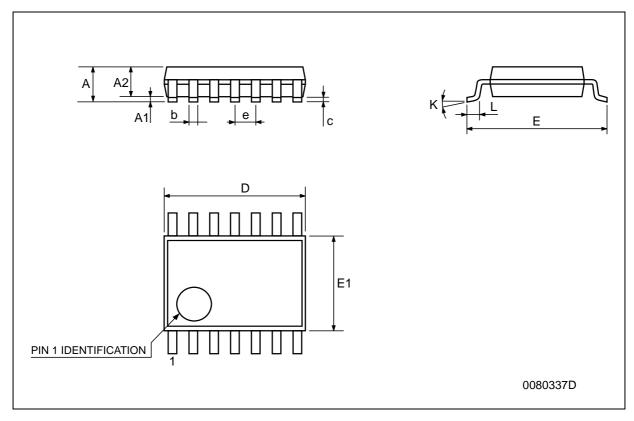
SO-14 MECHANICAL DATA

| DIM | | mm. | | | inch | |
|------|------|------|-------|--------|-------|-------|
| DIM. | MIN. | TYP | MAX. | MIN. | TYP. | MAX. |
| Α | | | 1.75 | | | 0.068 |
| a1 | 0.1 | | 0.2 | 0.003 | | 0.007 |
| a2 | | | 1.65 | | | 0.064 |
| b | 0.35 | | 0.46 | 0.013 | | 0.018 |
| b1 | 0.19 | | 0.25 | 0.007 | | 0.010 |
| С | | 0.5 | | | 0.019 | |
| c1 | | | 45° | (typ.) | • | • |
| D | 8.55 | | 8.75 | 0.336 | | 0.344 |
| Е | 5.8 | | 6.2 | 0.228 | | 0.244 |
| е | | 1.27 | | | 0.050 | |
| e3 | | 7.62 | | | 0.300 | |
| F | 3.8 | | 4.0 | 0.149 | | 0.157 |
| G | 4.6 | | 5.3 | 0.181 | | 0.208 |
| L | 0.5 | | 1.27 | 0.019 | | 0.050 |
| М | | | 0.68 | | | 0.026 |
| S | | - | 8° (ı | max.) | | 4 |



TSSOP14 MECHANICAL DATA

| DIM | | mm. | | inch | | | | |
|------|------|----------|------|-------|------------|--------|--|--|
| DIM. | MIN. | TYP | MAX. | MIN. | TYP. | MAX. | | |
| А | | | 1.2 | | | 0.047 | | |
| A1 | 0.05 | | 0.15 | 0.002 | 0.004 | 0.006 | | |
| A2 | 0.8 | 1 | 1.05 | 0.031 | 0.039 | 0.041 | | |
| b | 0.19 | | 0.30 | 0.007 | | 0.012 | | |
| С | 0.09 | | 0.20 | 0.004 | | 0.0089 | | |
| D | 4.9 | 5 | 5.1 | 0.193 | 0.197 | 0.201 | | |
| E | 6.2 | 6.4 | 6.6 | 0.244 | 0.252 | 0.260 | | |
| E1 | 4.3 | 4.4 | 4.48 | 0.169 | 0.173 | 0.176 | | |
| е | | 0.65 BSC | | | 0.0256 BSC | | | |
| К | 0° | | 8° | 0° | | 8° | | |
| L | 0.45 | 0.60 | 0.75 | 0.018 | 0.024 | 0.030 | | |



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